



TLC27L1, TLC27L1A, TLC27L1B

CMOS LOW POWER OPERATIONAL AMPLIFIERS

Description

The TLC27L1 operational amplifier combines a wide range of input offset-voltage grades with low offset-voltage drift and high input impedance. The TLC27L1 is a low-bias version of the TLC271 programmable amplifier.

Three offset-voltage grades are available, ranging from the low-cost TLC27L1 (10mV) to the TLC27L1B (2mV) low-offset version. The devices are offered in both commercial and industrial operating temperature ranges.

The extremely high input impedance and low bias currents, in conjunction with good common-mode rejection and supply voltage rejection, make these devices a good choice for new state-of-the-art designs as well as for upgrading existing designs.

The devices also exhibit low-voltage single-supply operation, with a common-mode input-voltage range including the negative rail.

Features

 Wide range of supply voltages over specified temperature range:

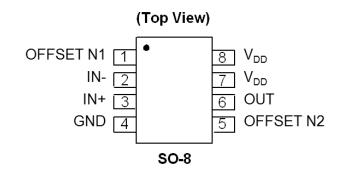
> 0°C to +70°C . . . 3 V to 16 V -40°C to +85°C . . . 4 V to 16 V

- Single-Supply Operation
- Common-Mode Input Voltage Range Extends Below the Negative Rail
- Low Noise:

68nV/√Hz typical @ f = 1kHz

- Output Voltage Range Includes Negative Rail
- High Input Impedance
- Designed-In Latch-Up Immunity
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

The TLC27L1 is the low power version of the TLC271. It offers low power for applications requiring long battery life. For applications that require more performance consider the TLC271.

The TLC27L1 is well suited to many consumer audio, industrial and other low power applications. Consider carefully the bandwidth and slew rate requirements for a specific application.

- Audio
 - Microphone Preamplifier
 - Filtering Equalizers
 - Signal Amplification
- Industrial
 - Power Supply
 - Instrumentation
 - Metering
- Medical

Portable Meters and Measurement Instrumentation

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Ordering Information

	Dookogo	Offset	Operating	Packaging	13" Tape a	nd Reel
Device	Package Code	Voltage	Temperature Range	(Note 4)	Quantity	Part Number Suffix
TLC27L1CS-13	S	10mV	0 to +70°C	SO-8	2500/Tape & Reel	-13
TLC27L1ACS-13	S	5mV	0 to +70°C	SO-8	2500/Tape & Reel	-13
TLC27L1BCS-13	S	2mV	0 to +70°C	SO-8	2500/Tape & Reel	-13
TLC27L1IS-13	S	10mV	-40 to +85°C	SO-8	2500/Tape & Reel	-13
TLC27L1AIS-13	S	5mV	-40 to +85°C	SO-8	2500/Tape & Reel	-13
TLC27L1BIS-13	S	2mV	-40 to +85°C	SO-8	2500/Tape & Reel	-13

Note:

Pin Descriptions

Pin Name	Pin Number	Description
OFFSET N1	1	Offset Control Inverting Input
IN-	2	Inverting Input
IN+	3	Non-Inverting Input
GND	4	Ground
OFFSET N2	5	Offset Control Non-Inverting Input
OUT	6	Output
V_{DD}	7	Supply
V_{DD}	8	Supply

^{4.} Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



Absolute Maximum Ratings (Notes 5, 6, 7, 8, 9)

Symbol	P	arameter	Rating	Unit
V_{DD}	Supply Voltage: (Note 6)		18	V
V_{ID}	Differential Input Voltage (Note 7)		±V _{DD}	V
V _{IN}	Input Voltage Range (either input)		-0.3 to V _{DD}	V
I _{IN}	Input Current	Input Current		
Ιο	Output current	±30	mA	
	Output Short-Circuit to GND (Note	Continuous	_	
P_D	Power Dissipation (Note 9)		1065	mW
-	On and the Tanana and the Danier	C Grade	0 to +70	
T_A	Operating Temperature Range	I Grade	-40 to +85	°C
T_J	Operating Junction Temperature	Operating Junction Temperature		
T _{ST}	Storage Temperature Range		-65 to +150	°C
ESD HBM	Human Body Model ESD Protection	n (1.5kΩ in series with 100pF)	1.5	kV

Notes:

- 5. Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- All voltage values, except differential voltages, are with respect to ground.
 Differential input voltages are at IN+ with respect to IN-.
- 8. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.
- 9. For operating at high temperatures, the TLC27L1 must be derated 8.5mW/°C to zero based on a +150°C maximum junction temperature and a thermal resistance of +117 °C/W when the device is soldered to a printed circuit board, operating in a still air ambient.

Recommended Operating Conditions

Sumbal	Symbol Parameter -		C gı	C grade		I grade		
Symbol			Min	Max	Min	Max	_	
V _{DD}	Supply Voltage		3	16	4	16	V	
V _{IC}	Common Mode Input Voltage	$V_{DD} = 5V$	-0.2	3.5	-0.2	3.5	V	
		$V_{DD} = 10V$	-0.2	8.5	-0.2	8.5		
T _A	Operating Free Air Temperature		0	+70	-40	+85	°C	



					TL	.C27L1C	C, TLC2	7L1AC,	TLC27L	1BC	
	Parameter		Conditions	T _A	,	V _{DD} = 5V	,		V _{DD} = 10	V	Unit
					Min	Тур	Max	Min	Тур.	Max	
		TI 007140		+25°C	_	1.1	10	_	1.1	10	
		TLC27L1C	$V_0 = 1.4V$	0 to +70°C	_	_	12	_		12	
V	land Office Valtage	TI 0071 4 4 0	$V_{IC} = 0V$	+25 [°] C		0.9	5		0.9	5	>/
V _{IO}	Input Offset Voltage TLC27L1AC		$R_S = 50\Omega$	0 to +70°C		_	6.5	_		6.5	mV
		TI C071 4DC	$R_L = 1M\Omega$	+25°C	_	0.24	2	_	0.26	2	
		TLC27L1BC		0 to +70°C		_	3	_		3	
α_{VIO}	Average Temperature Input Offset Voltage	e Coefficient of		+25 to +70°C		1.1			1		μV/°C
			$V_O = V_{DD}/2$,	+25°C	_	0.1	60	_	0.1	60	
I _{IO}	Input Offset Current	(Note 10)	$V_{IC} = V_{DD}/2$	+70°C	_	7	300	_	8	300	pА
			$V_O = V_{DD}/2$,	+25°C	_	0.6	60	_	0.7	60	
I _{IB}	Input Bias Current (Note 10)		$V_{IC} = V_{DD}/2$	+70°C	_	40	600	_	50	600	pА
				+25°C	-0.2 to	-0.3 to	_	-0.2 to	-0.3 to 9.2	_	V
V _{ICR}	V _{ICR} Common Mode Input V	Voltage (Note 11)	_	0°C to +70°C	-0.2 to 3.5		_	-0.2 to 8.5			V
			., ,,,,	+25°C	3.2	4.1	_	8	8.9	_	
V_{OH}	High Level Output Vo	ltage	$V_{ID} = 100 \text{mV},$ $R_L = 1 \text{M}\Omega$	0°C	3	4.1	_	7.8	8.9	_	V
				+70°C	3	4.2	_	7.8	8.9	_	
			1001	+25 [°] C		0	50		0	50	
V_{OL}	Low Level Output Vo	ltage	$V_{ID} = -100 \text{mV},$	0°C	_	0	50	_	0	50	mV
			$I_{OL} = 0$	+70°C		0	50	_	0	50	
			D = 4MO	+25°C	50	520	_	50	870		
A_{VD}	Large Signal Differen	tial Voltage Gain	$R_L = 1M\Omega$ (Note 12)	0°C	50	700	_	50	1030		V/mV
			(Note 12)	+70°C	50	380	_	50	660		
				+25°C	65	94	_	65	97		
CMRR	Common Mode Rejec	ction Ratio	$V_{IC} = V_{ICRmin}$	0°C	60	95	_	60	97		dB
				+70°C	60	95	_	60	97		
	Cumply Valtage Dele	ntion Datic	$V_{DD} = 5V \text{ to}$	+25°C	70	97	_	70	97		
k _{SVR}	Supply Voltage Reject (ΔV _{DD} /ΔV _{IO})	HIOH KATIO	10V	0°C	60	97	_	60	97	_	dB
	(\(\triangle \neq \text{DD} \(\triangle \neq \text{DD} \(\triangle \neq \text{DO} \)		V _O = 1.4V	+70°C	60	98	_	60	98		
			$V_O = V_{DD}/2$,	+25°C	_	10	17	_	14	23	
I_{DD}	Supply Current		$V_{IC} = V_{DD}/2$,	0°C	_	12	21	_	18	33	μΑ
			No Load	+70°C		8	14	_	11	20	

Notes:

^{10.} The typical values of input bias current and input offset current below 5pA were calculated.

^{11.} This range also applies to each input individually.

^{12.} At $V_{DD} = 5V$, $V_0 = 0.25V$ to 2V; at $V_{DD} = 10V$, $V_0 = 1V$ to 6V.



					1	LC27L1	I, TLC2	7L1AI, 1	TLC27L	1BI	
	Parameter		Conditions	T _A	,	V _{DD} = 5\	,		V _{DD} = 10	V	Unit
					Min	Тур	Max	Min	Тур.	Max	
		TI 0071 41		+25°C	_	1.1	10	_	1.1	10	
		TLC27L1I	V _O = 1.4V	-40° to 85°C	_	_	13	_	_	13	
\/	Lamest Office () / eller are	TI 0071 4 4 1	$V_{IC} = 0V$	+25°C	_	0.9	5	_	0.9	5	>/
V _{IO}	Input Offset Voltage	TLC27L1AI	$R_S = 50\Omega$	-40° to +85°C	_	_	7	_	_	7	mV
		TI COZI 4DI	$R_L = 1M\Omega$	+25°C		0.24	2		0.26	2	
	TLC27L1BI		-40° to +85°C		_	3.5	_		3.5		
α_{VIO}	Average Temperature Coefficient of Input Offset Voltage		_	+25°C to +85°C		1.1			1		μV/°C
	Input Offset Current (Note 13) Input Bias Current (Note 13)		$V_O = V_{DD}/2$	+25°C	_	0.1	60	_	0.1	60	0
I _{IO}			$V_{IC} = V_{DD}/2$	+85°C	_	24	1000	_	26	1000	pA
			$V_O = V_{DD}/2$	+25°C	_	0.6	60	_	0.7	60	
I _{IB}			$V_{IC} = V_{DD}/2$	+85°C	_	200	2000	_	220	2000	pА
.,	Common Mode Input Voltage (Note 14)			+25°C	-0.2 to	-0.3 to	_	-0.2 to	-0.3 to 9.2	_	V
V _{ICR}			_	-40° to +85°C	-0.2 to	_	_	-0.2 to 8.5	_	_	V
			\/ 400m\/ D	+25°C	3	4.1	_	8	8.9	_	
V_{OH}	High Level Output Vol	tage	$V_{ID} = 100 \text{mV}, R_L = 100 \text{mV}$	-40°C	3	4.1	_	7.8	8.9	_	V
			1ΜΩ	+85°C	3	4.2		7.8	8.9		
			100 11	+25°C	_	0	50	_	0	50	
V_{OL}	Low Level Output Volt	age	$V_{ID} = -100 \text{mV},$ $I_{OL} = 0$	-40°C	_	0	50	_	0	50	mV
			IOL = U	+85°C	_	0	50	_	0	50	
	0' D'(()'	-1.)/-11	$R_L = 1M\Omega$	+25°C	50	520	_	50	870		
A_{VD}	Large Signal Differenti Gain	ai voitage	(Note 15)	-40°C	50	900	_	50	1550		V/mV
	Gaiii		(Note 15)	+85°C	50	330	_	50	585		
				+25°C	65	94	_	65	97	_]
CMRR	Common Mode Reject	tion Ratio	$V_{IC} = V_{ICRmin}$	-40°C	60	95	_	60	97	_	dB
				+85°C	60	95	_	60	98	_	
	Complex Valtage Dailers	ion Dotio	\/ - F\/ to 10\/	+25°C	70	97	_	70	97		
k _{SVR}	Supply Voltage Rejection Ratio		$V_{DD} = 5V \text{ to } 10V$	-40°C	60	97	_	60	97	_	dB
	$(\Delta V_{DD}/\Delta V_{IO})$		V _O = 1.4V	+85°C	60	98	_	60	98	_	
			$V_O = V_{DD}/2$	+25°C	_	10	17	_	14	23	
I_{DD}	Supply Current		$V_{IC} = V_{DD}/2$	-40°C	_	16	27	_	25	43	μΑ
			No load	+85°C	_	17	13	_	10	18	

Notes:

^{13.} The typical values of input bias current and input offset current below 5pA were calculated.

^{14.} This range also applies to each input individually.

^{15.} At $V_{DD} = 5V$, $V_O = 0.25V$ to 2V; at $V_{DD} = 10V$, $V_O = 1V$ to 6V.



Parameter		Conditions		TA	TLC27L1C, TLC27L1AC, TLC27L1BC			Unit
					Min	Тур	Max	_
				+25°C	_	0.03	_	
		$R_L = 1M\Omega$	$V_{I(PP)} = 1V$	0°C	_	0.04	_	
SR	Class Data at Haits Cain	C _L = 20pF		+70°C	_	0.03	_	\//
SK	Slew Rate at Unity Gain	See		+25°C	_	0.03	_	V/µ
		Figure 31	$V_{I(PP)} = 2.5V$	0°C	_	0.03	_	
			+70°C	_	0.02	_		
Vn	Equivalent Input Noise Voltage	$F = 1kHz$, $R_S = 20\Omega$ See Figure 32		+25°C	_	68	_	nV/√
				+25°C	_	5	_	kHz
Зом	Maximum Output Swing Bandwidth		= 20pF, R _L = 1MΩ	0°C	_	6	_	
	Dandwidth	See Figure 3	ı	+70°C	_	4.5	_	
		1011-0	00-F	+25°C	_	85	_	
B ₁	Unity Gain Bandwidth	$V_1 = 10 \text{mV}, C$	•	0°C		100		МН
		See Figure 3	3	+70°C	_	65	_	1
		E D V 4	0)/ 0005	+25°C	_	34°	_	
фm	Phase Margin		$0mV$, $C_L = 20pF$	0°C		36°		_
		See Figure 33		+70°C	_	30°	_	

	Parameter	Conditions		TA	TLC2	TLC27L1C, TLC27L1AC, TLC27L1BC		
					Min	Тур	Max	_
				+25°C	_	0.05	_	
		$R_L = 1M\Omega$,	$V_{I(PP)} = 1V$	0°C	_	0.05	_	
0.0	Olava Data at Haita Oaia	C _L = 20pF See		+70°C	_	0.04	_	\ // ₂
SR	Slew Rate at Unity Gain			+25°C	_	0.04	_	V/µs
	Figure 31	Figure 31	$V_{I(PP)} = 5.5V$	0°C	_	0.05	_	- -
				+70°C	_	0.04	_	
V _n	Equivalent Input Noise Voltage	$F = 1kHz$, $R_S = 20\Omega$ See Figure 32		+25°C	_	68	_	nV/√Hz
				+25°C	_	1	_	
Вом	Maximum Output Swing		20pF, $R_L = 1M\Omega$	0°C	_	1.3	_	kHz
	Bandwidth	See Figure 31		+70°C	_	0.9	_	
				+25°C	_	110	_	
B ₁	Unity Gain Bandwidth	$V_I = 10 \text{mV}, C_L$	= 20pF	0°C	_	125	_	MHz
	·	See Figure 33		+70°C	_	90	_	1
				+25°C	_	38°	_	
фт	Phase Margin		$F = B_1, V_1 = 10 \text{mV}, C_L = 20 \text{pF}$		_	40°	_	1 _ [
		See Figure 33		+70°C	_	34°	_	1



_{DD} = 5	Parameter		Conditions	T _A	TLC2	7L1I, TLC27 TLC27L1BI	L1AI,	Unit
					Min	Тур	Max	_
				+25°C	_	0.03	_	
		$R_L = 1M\Omega$	$V_{I(PP)} = 1V$	-40°	_	0.04	_	
		$C_L = 20pF$,	+85°C	_	0.03	_	
SR	Slew Rate at Unity Gain	See		+25°C	_	0.03	_	V/µs
		Figure 31	$V_{I(PP)} = 2.5V$	-40°	_	0.04	_	
			,	+85°C	_	0.02	_	
Vn	Equivalent Input Noise Voltage	F = 1kHz, R _s See Figure 3	$F = 1 \text{kHz}, R_S = 20\Omega$ See Figure 32		_	68	_	nV/√Hz
			3		_	5	_	
B _{OM}	Maximum Output Swing		= 20pF, R_L = 1M Ω	-40°	_	7	_	kHz
0	Bandwidth	See Figure 3	1	+85°C	_	4	_	
				+25°C	_	85	_	
B₁	Unity Gain Bandwidth	$V_I = 10 \text{mV}, C$		-40°	_	130	_	MHz
·		See Figure 3	3	+85°C	_	55	_	1
				+25°C	_	34°	_	
фт	Phase Margin		$0mV, C_L = 20pF$ See	-40°	_	38°	_	1 _
•		Figure 33		+85°C	_	28°	_	
/ _{DD} = 1	0V	l .		<u> </u>				
					TLC27L1I, TLC27L1AI, TLC27L1BI			Unit
	Parameter		Conditions	T _A				
					Min	Тур	Max	_
				+25°C	_	0.05	_	
		$R_L = 1M\Omega$	$V_{I(PP)} = 1V$	-40°	_	0.06	_	
SR	Slew Rate at Unity Gain	$C_L = 20pF$		+85°C	_	0.03	_	\//v.o
SK	Siew Rate at Officy Gain	See		+25°C		0.04		V/µs
		Figure 31	$V_{I(PP)} = 5.5V$	-40°	_	0.05	_	
				+85°C		0.03		
								->///
Vn	Equivalent Input Noise Voltage	$F = 1kHz, R_s$ See Figure 3		+25°C		68		nV/√Hz
Vn		See Figure 3	2	+25°C +25°C	<u> </u>	68 1		NV/√HZ
V _n	Maximum Output Swing	See Figure 3: $V_O = V_{OH}, C_L$	= 20pF, R_L = 1M Ω					hV/\Hz
		See Figure 3	= 20pF, R_L = 1M Ω	+25°C	_ 	1	_ 	
	Maximum Output Swing	See Figure 3: $V_O = V_{OH}, C_L$ See Figure 3	2 = 20pF, R _L = 1MΩ 1	+25°C -40°		1 1.4		
	Maximum Output Swing	See Figure 3: $V_O = V_{OH}, C_L$ See Figure 3: $V_I = 10mV, C_L$	$= 20pF, R_L = 1M\Omega$ 1 $L = 20pF$	+25°C -40° +85°C	_	1 1.4 0.8	_	
Вом	Maximum Output Swing Bandwidth	See Figure 3: $V_O = V_{OH}, C_L$ See Figure 3	$= 20pF, R_L = 1M\Omega$ 1 $L = 20pF$	+25°C -40° +85°C +25°C	_	1 1.4 0.8 110	_	kHz
Вом	Maximum Output Swing Bandwidth	See Figure 3: $V_O = V_{OH}, C_L$ See Figure 3: $V_I = 10 \text{mV}, C$ See Figure 3:	$= 20pF, R_L = 1M\Omega$ 1 $L = 20pF$	+25°C -40° +85°C +25°C -40°		1 1.4 0.8 110 155		kHz
Вом	Maximum Output Swing Bandwidth	See Figure 3: $V_O = V_{OH}, C_L$ See Figure 3: $V_I = 10 \text{mV}, C$ See Figure 3:	$= 20pF, R_L = 1M\Omega$ 1 $L = 20pF$	+25°C -40° +85°C +25°C -40° +85°C	- - - -	1 1.4 0.8 110 155 80	_ 	kHz



Typical Performance Characteristics Table Index of Graphs

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		vs. Capacitive Load	27
V _n	Equivalent Input Noise Voltage	vs. Frequency	28
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Distribution of TLC27L1 Input Offset Voltage

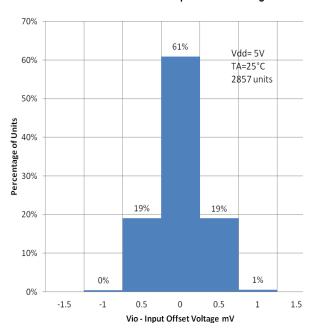


Figure 1

High-Level output voltage

High-Level output current 5 N-bigh 4 VDD=5V VDD=4V VDD=3V VDD=3V IoH - High-Level Output current-mA

Figure 3

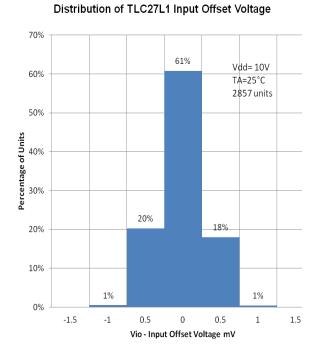


Figure 2

High-Level output voltage vs High-Level output current

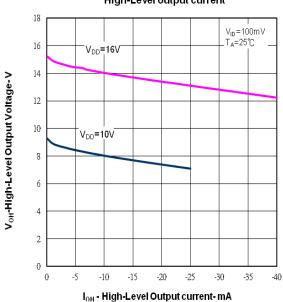


Figure 4



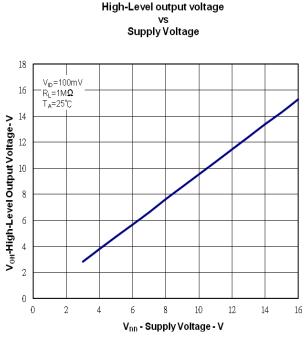
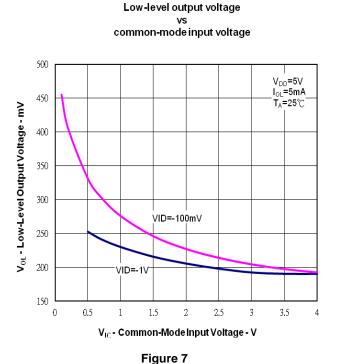


Figure 5



High-Level output voltage vs Free Air Temperature

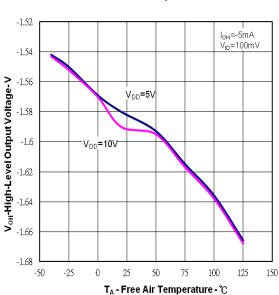


Figure 6

Low-level output voltage vs common-mode input voltage

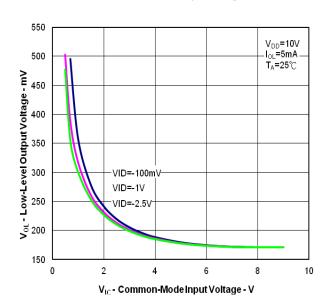


Figure 8



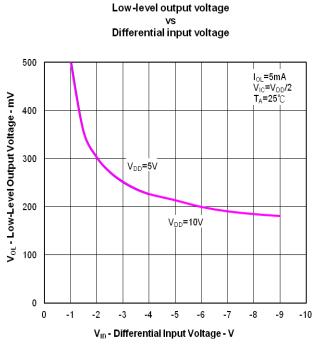


Figure 9

Low-level output voltage

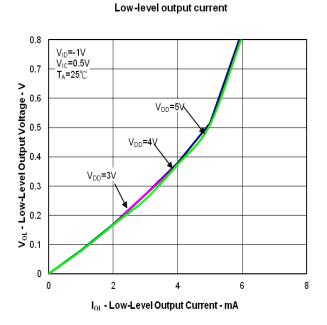
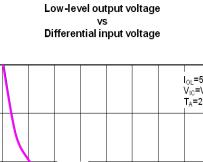


Figure 11



500

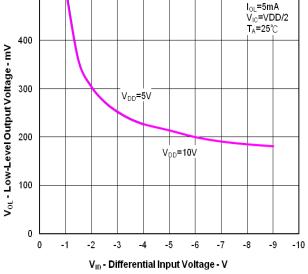
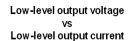


Figure 10



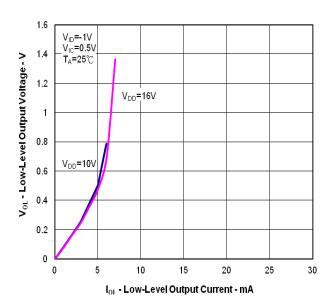


Figure 12



Large-Signal Differential Voltage Amplification vs Supply Voltage

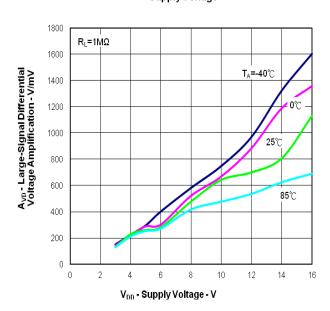


Figure 13

Input Bias Current and Input Offset Current vs Free-Air Temperature

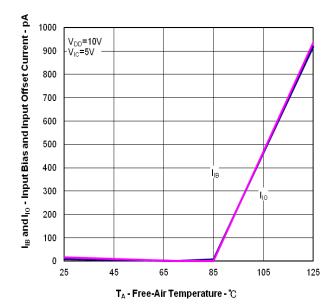


Figure 15

Large-Signal Differential Voltage Amplification vs Free-Air Temperature

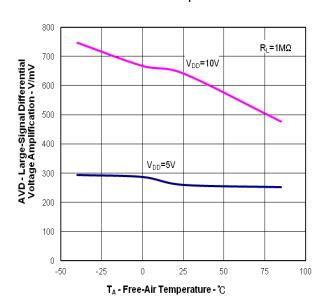


Figure 14

Common-mode input voltage (positive limit) vs Supply Voltage

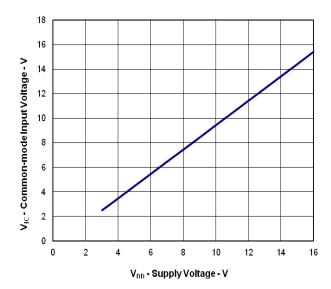


Figure 16



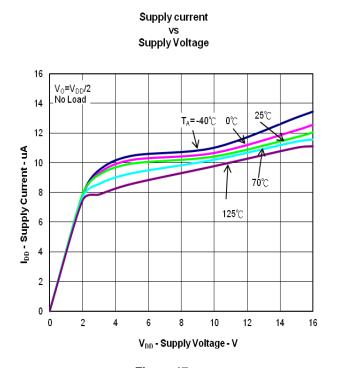


Figure 17

Slew Rate

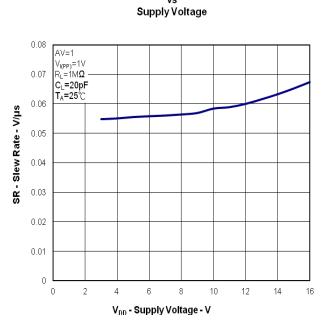
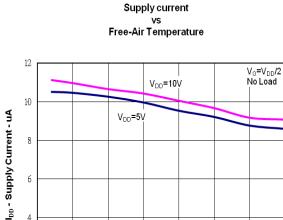


Figure 19



2

-50

0 25 50 75 100 T_A - Free-Air Temperature - °C

125



Figure 18

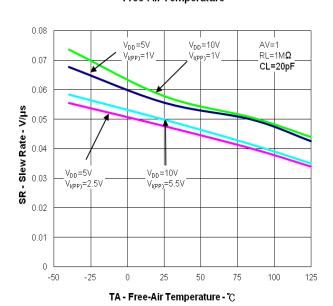


Figure 20



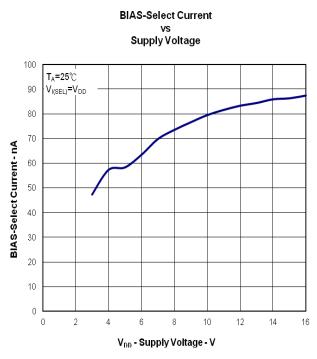


Figure 21

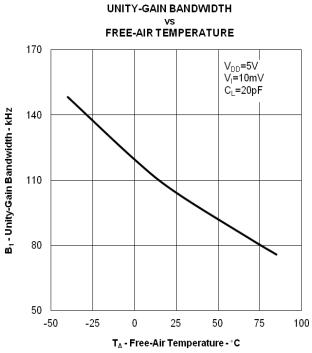


Figure 23

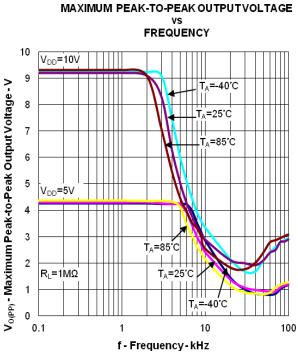


Figure 22

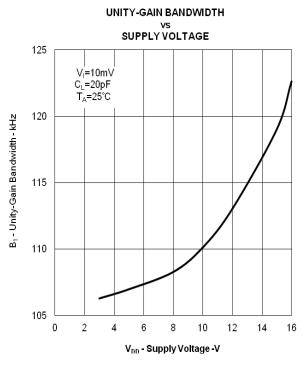


Figure 24



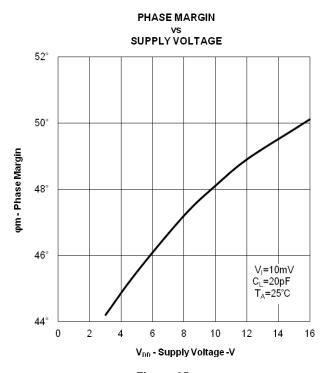


Figure 25

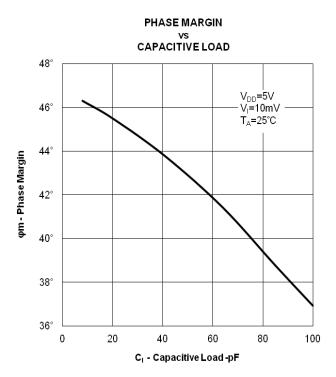


Figure 27

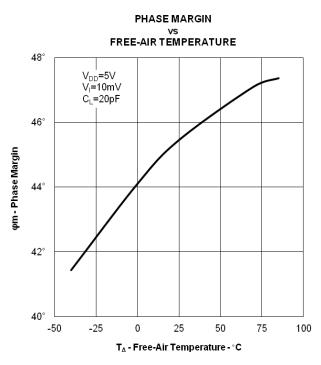


Figure 26

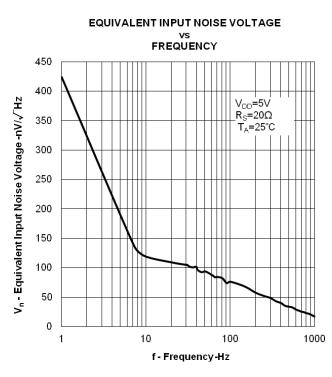


Figure 28



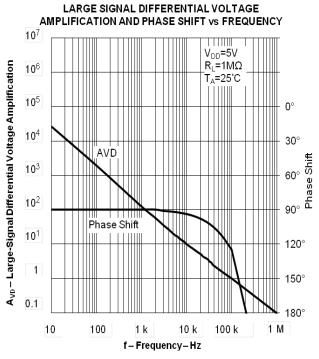


Figure 29

LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT VS FREQUENCY

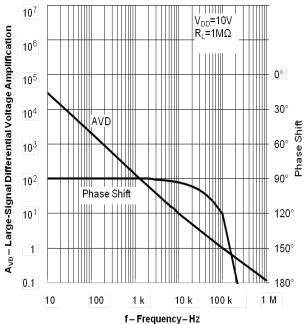


Figure 30



Application Information

Parameter measurement circuits

Because the TLC271 is optimized for single-supply operation, circuit configurations used for the various tests can present some difficulties since the input signal must be offset from ground. This issue can be avoided by testing the device with split supplies and the output load tied to the negative rail. Example circuits are shown below.

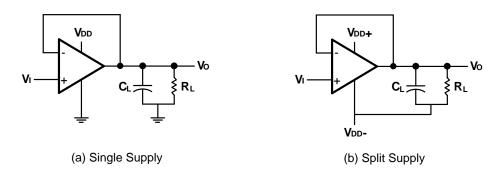


Figure 31 Measurement circuit with either single or split supply

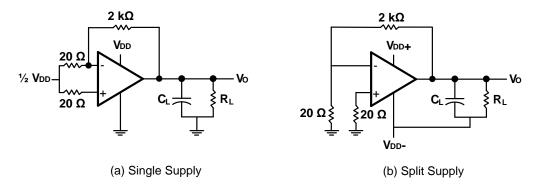


Fig 32 Noise measurement with single or split supply

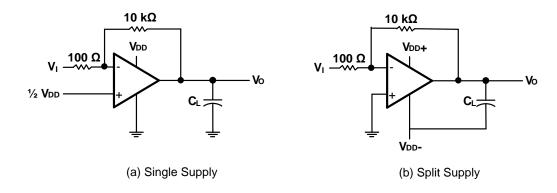


Figure 33 Gain of 100 with single or split supply



Application Notes

Offset Voltage Nulling Circuit

The TLC27L1 offers external input offset null control. Nulling of the input off set voltage may be achieved by adjusting a $100-k\Omega$ potentiometer connected between the offset null terminals with the wiper connected as shown in Figure 31.

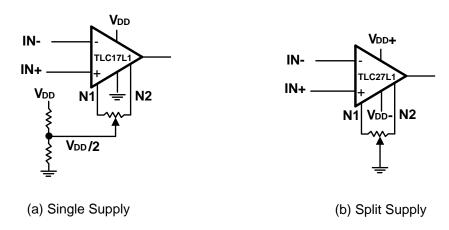


Figure 31 Offset Nulling Circuits

Input Bias Current - Error Protection

The TLC27L1 has an extremely high input impedance. To use the inputs as a high impedance node, for example, greater than100K, or to accurately measure bias current, it is necessary to place a guard ring around the input pins and drive the ring to a potential equivalent to the common mode input voltage. In many cases this common mode potential may exist as a part of the feedback circuit and can be obtained from one of the appropriate nodes. In the case for the SO8 package, pin 4 is connected to ground or Vdd-. Input pins 2 and 3 are normally well above the voltage on pin 4, so a large potential voltage on the order of several volts is likely between pins 3 and 4. To prevent interference with a 1 pA bias current, the board resistance will need to be in the order of gigaohms to have a minimum impact. The goal is to have the common mode potential on the guard ring, therefore reducing the stray voltage near the input pins to millivolts in normal applications. Any solder flux residue, excess moisture, humidity or board contamination will be detrimental to using the device in a high impedance input mode.

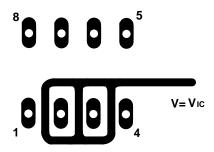


Figure 32 Bias Current Guarding for High Input Impedance Applications



Typical Application Circuits

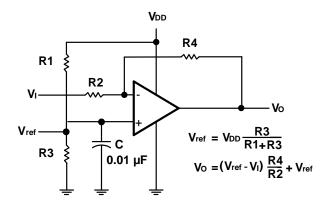


Figure 33 Inverting Amplifier With Voltage Reference

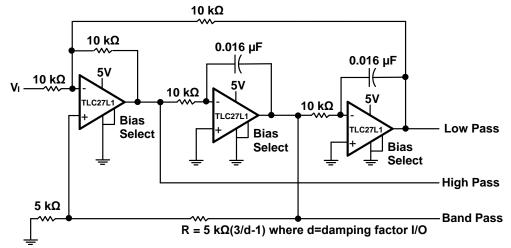


Figure 34 State Variable Filter

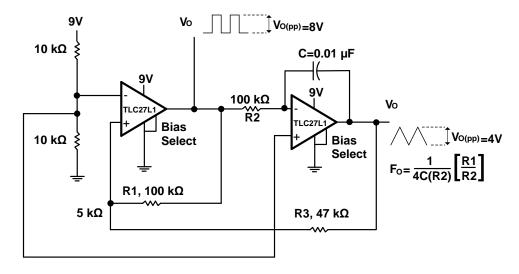


Figure 35 Single Supply Function Generator



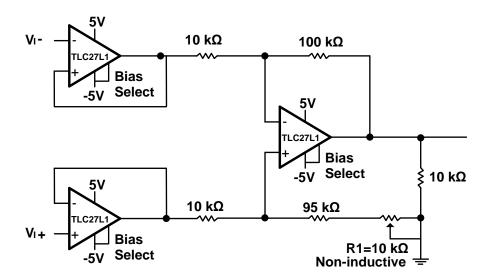


Figure 36 Low Power Instrumentation Amplifier

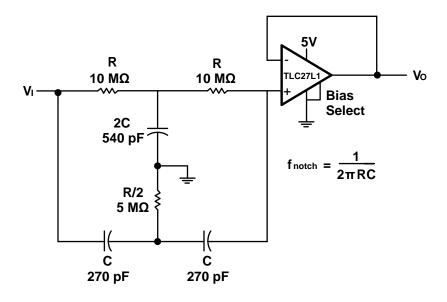


Figure 37 Single Supply Twin-T Notch Filter



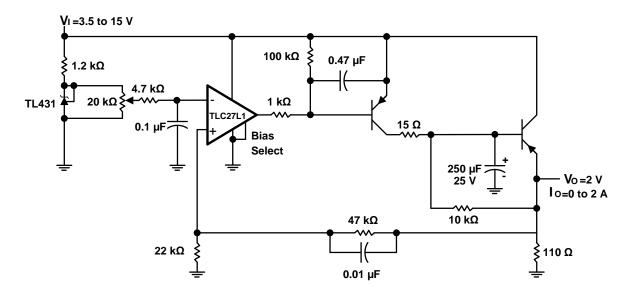


Figure 38 Power Supply

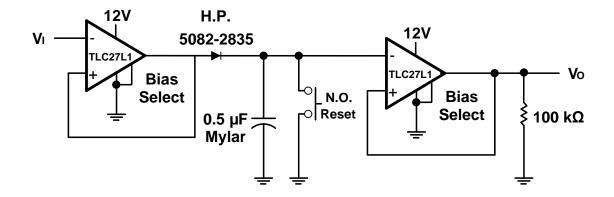


Figure 39 Positive Peak Detector



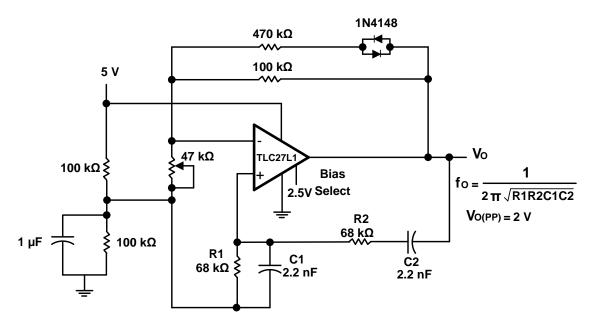


Figure 40 Wein Oscillator

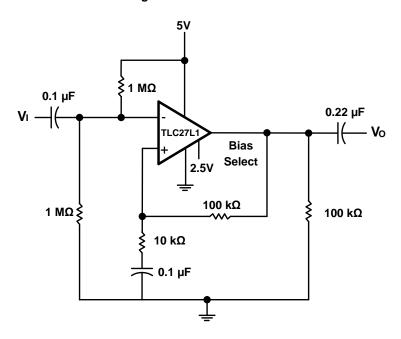


Figure 41 Single-Supply AC Amplifier



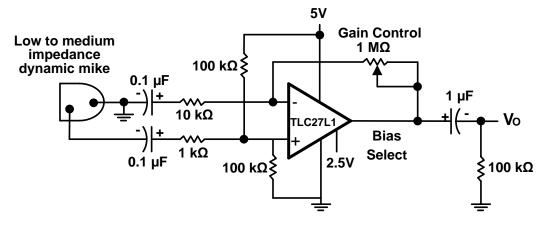


Figure 42 Microphone Preamplifier

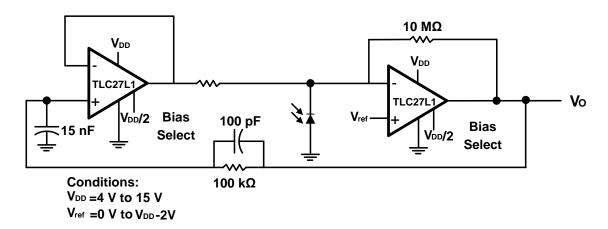


Figure 43 Photo-Diode Amplifier With Ambient Light Rejection

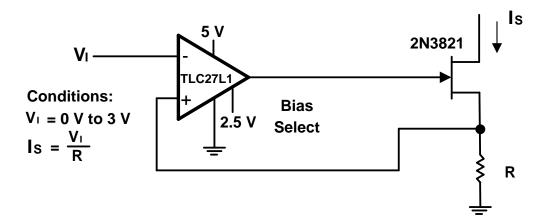
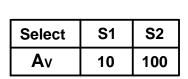


Figure 44 Precision Low-Current Sink





 $V_{DD} = 5 V \text{ to } 12 V$

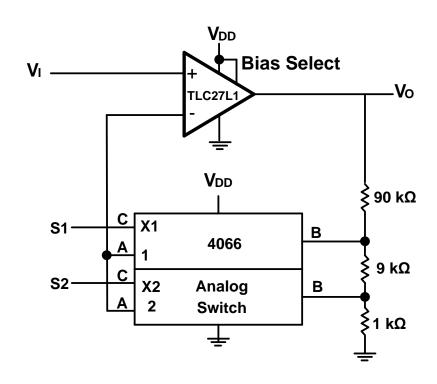
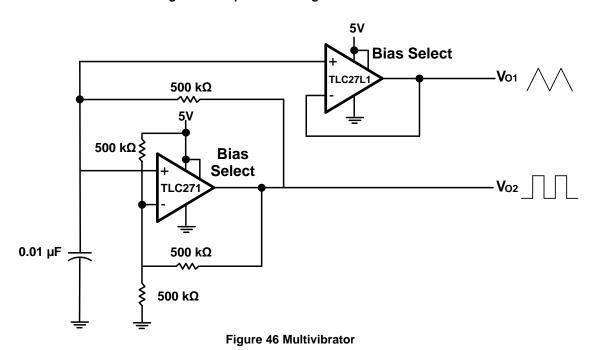


Figure 45 Amplifier With Digital Gain Selection





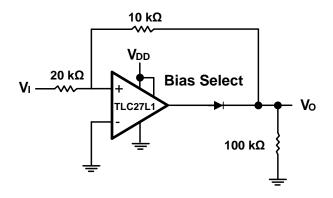
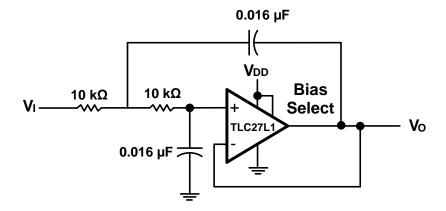


Figure 47 Full Wave Rectifier



Nomalized to Fc= 1 kHz and R \perp = 10 k Ω

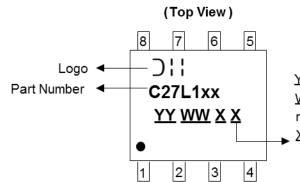
Figure 48 Two-Pole Low-Pass Butterworth Filter



Marking Information

SO-8

Part mark	Part number
C27L1C	TLC27L1CS
C27L1AC	TLC27L1ACS
C27L1BC	TLC27L1BCS
C27L1I	TLC27L1IS
C27L1AI	TLC27L1AIS
C27L1BI	TLC27L1BIS



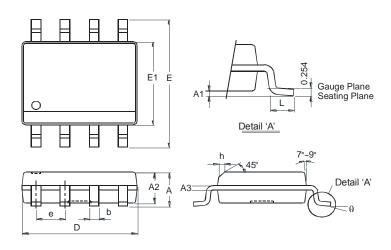
<u>YY</u>: Year: 08, 09,10~ <u>WW</u>: Week: 01~52; 52 represents 52 and 53 week

X : Internal Code

Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

Package Type: SO-8



	SO-8	
Dim	Min	Max
Α	-	1.75
A1	0.10	0.20
A2	1.30	1.50
A3	0.15	0.25
b	0.3	0.5
D	4.85	4.95
E	5.90	6.10
E1	3.85	3.95
е	1.27	Тур
h	-	0.35
L	0.62	0.82
θ	0°	8°
All Di	mensions	in mm



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